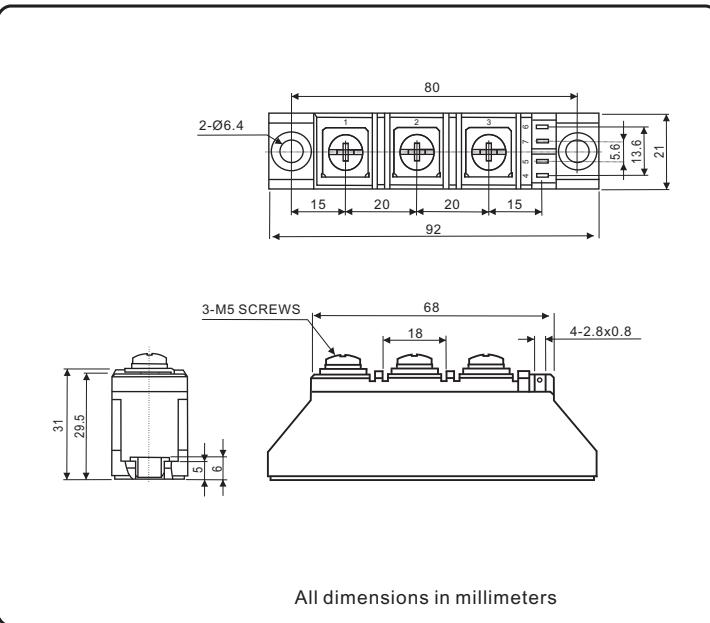


Thyristor/Diode and Thyristor/Thyristor, 90A (ADD-A-PAK Power Modules)


ADD-A-PAK

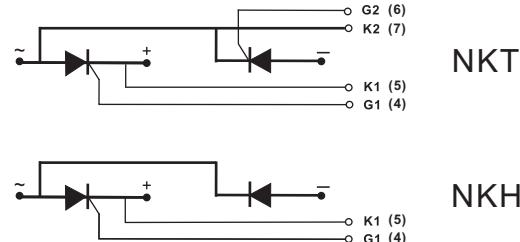
FEATURES

- High voltage
- Electrically isolated by DBC ceramic (Al_2O_3)
- 3000 V_{RMS} isolating voltage
- Industrial standard package
- High surge capability
- Glass passivated chips
- Modules uses high voltage power thyristor/diodes in two basic configurations
- Simple mounting
- UL approved file E320098 
- Compliant to RoHS
- Designed and qualified for multiple level



APPLICATIONS

- DC motor control and drives
- Battery charges
- Welders
- Power converters
- Lighting control
- Heat and temperature control



PRODUCT SUMMARY	
I _{T(AV)}	90 A

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUE	UNITS
I _{T(AV)}	85 °C	90	A
I _{T(RMS)}	85 °C	141	
I _{TSM} /I _{FSM}	50 Hz	2000	A
	60 Hz	2100	
I ² t	50 Hz	20	kA ² s
	60 Hz	18.3	
I ² \sqrt{t}		200	kA ² \sqrt{s}
V _{DRM} / V _{RRM}	Range	400 to 1600	V
T _J	Range	-40 to 125	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V_{RRM}/V_{DRM}, MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM}/V_{DSM}, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM}/I_{DRM} AT 125 °C mA
NKT90..A NKH90..A	04	400	500	10
	08	800	900	
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

FORWARD CONDUCTION								
PARAMETER	SYMBOL	TEST CONDITIONS			VALUE	UNITS		
Maximum average on-state current at case temperature	I _{T(AV)}	180° conduction, half sine wave ,50Hz			90	A		
					85	°C		
Maximum RMS on-state current	I _{T(RMS)}	180° conduction, half sine wave ,50Hz, T _C = 85°C			141	A		
Maximum peak, one-cycle, on-state non-repetitive surge current	I _{TSM}	t = 10 ms	No voltage reapplied	Sine half wave, initial T _J = T _J maximum	2000	A		
		t = 8.3 ms			2100			
Maximum I ² t for fusing	I ² t	t = 10 ms	100% V _{RRM} reapplied	Sine half wave, initial T _J = T _J maximum	20	kA ² s		
		t = 8.3 ms			18.3			
		t = 10 ms			14			
		t = 8.3 ms			12.8			
Maximum I ² \sqrt{t} for fusing	I ² \sqrt{t}	t = 0.1 ms to 10 ms, no voltage reapplied			200	kA ² \sqrt{s}		
Maximum on-state voltage drop	V _{TM}	I _{TM} = 270A , T _J = 25 °C, 180° conduction			1.6	V		
Maximum forward voltage drop	V _{FM}	I _{FM} = 270A , T _J = 25 °C, 180° conduction			1.3			
Maximum holding current	I _H	Anode supply = 6 V, resistive load T _J = 25 °C			150	mA		
Maximum latching current	I _L	Anode supply = 6 V resistive load, T _J = 25 °C			400			

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum peak reverse and off-state leakage current	I _{RRM} I _{DRM}	T _J = 125 °C		10	mA
RMS isolation Voltage	V _{ISO}	50 Hz, circuit to base, all terminals shorted		2500 (1min) 3000 (1s)	V
Critical rate of rise of off-state voltage	dV/dt	T _J = T _J maximum, exponential to 67 % rated V _{DRM}		500	V/ μ s

TRIGGERING						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum peak gate power	P _{GM}	$t_p \leq 5 \text{ ms}$, T _J = T _J maximum		10	W	
Maximum average gate power	P _{G(AV)}	f = 50 Hz, T _J = T _J maximum		3		
Maximum peak gate current	I _{GM}	$t_p \leq 5 \text{ ms}$, T _J = T _J maximum		3	A	
Maximum peak negative gate voltage	-V _{GT}			10	V	
Maximum required DC gate voltage to trigger	V _{GT}	T _J = 25 °C	Anode supply = 6 V, resistive load; R _a = 1 Ω	0.7~1.6		
Maximum required DC gate current to trigger	I _{GT}			20~100	mA	
Maximum gate voltage that will not trigger	V _{GD}	T _J = T _J maximum, 66.7% V _{DRM} applied		0.25	V	
Maximum gate current that will not trigger	I _{GD}			10	mA	
Maximum rate of rise of turned-on current	dI/dt	T _J = 25°C, I _{GM} = 1.5A, t _r ≤ 0.5 μs		150	A/μs	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction operating temperature range	T _J			- 40 to 125	°C
Maximum storage temperature range	T _{Stg}			- 40 to 150	
Maximum thermal resistance, junction to case per junction	R _{thJC}	DC operation		0.28	°C/W
Maximum thermal resistance, case to heatsink per module	R _{thCS}	Mounting surface, smooth, flat and greased		0.077	
Mounting torque ± 10 % AAP to heatsink, M6 busbar to AAP, M5		A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. Lubricated threads.		4	N.m
Approximate weight				120	g
				4.23	oz.
Case style				ADD-A-PAK	

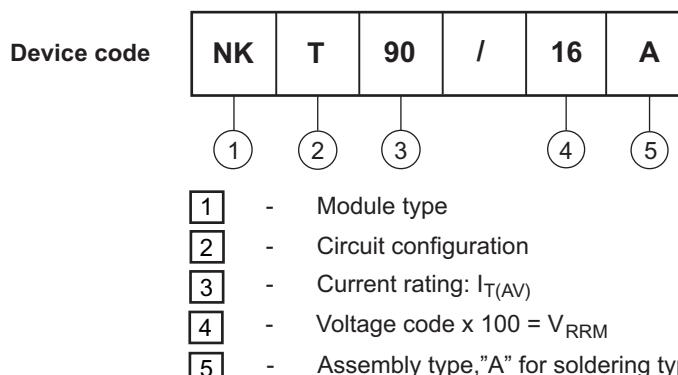
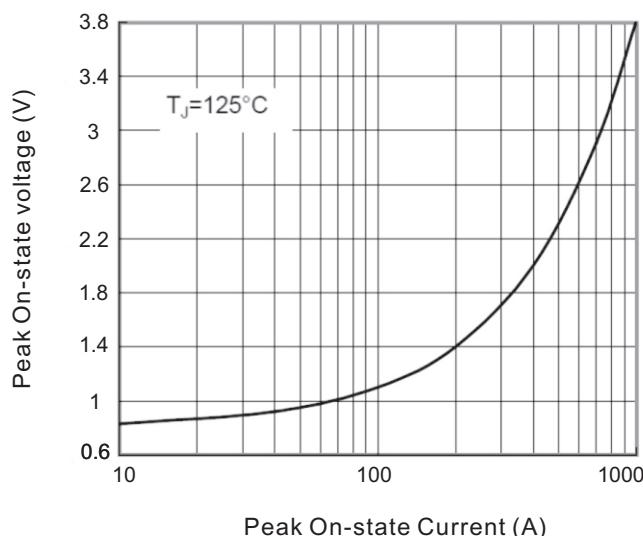
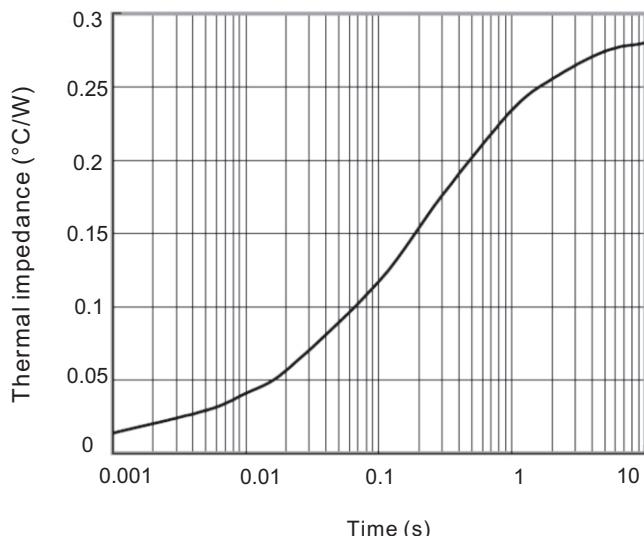
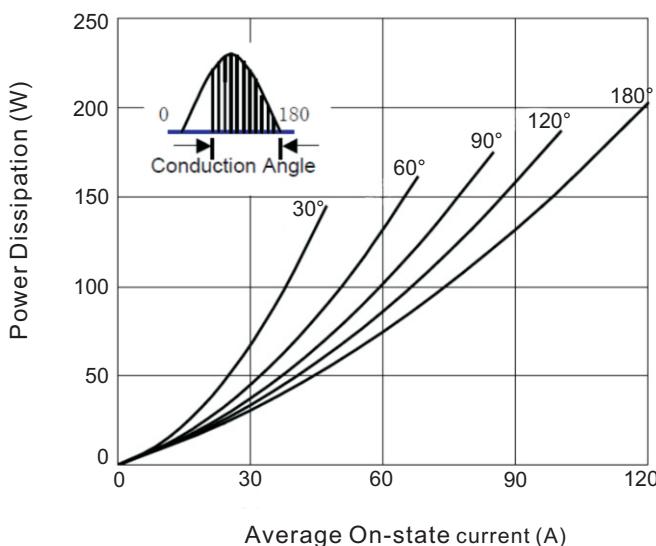
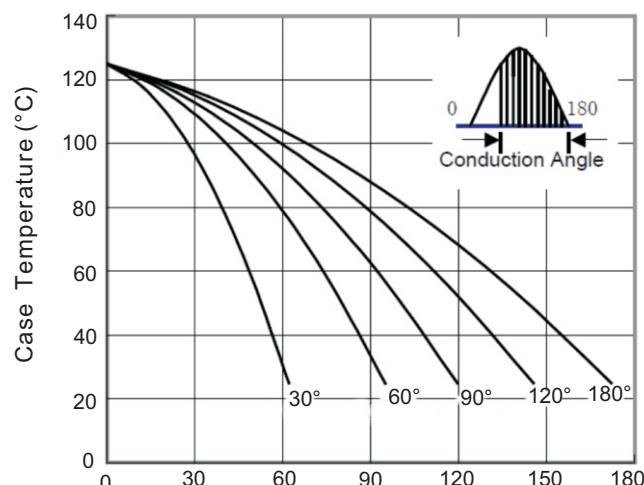
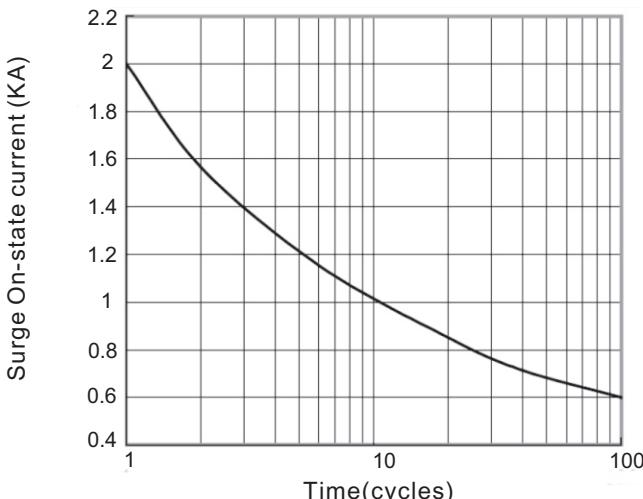
ORDERING INFORMATION TABLE


Fig.1 Peak On-state Voltage vs. Peak On-state Current

Fig.2 Max. Thermal Impedance (Junction To case) Vs. Time

Fig.3 Power Dissipation Vs. Average On-state Current

Fig.4 Case Temperature Vs. Average On-state Current

Fig.5 Surge On-state Current Vs. Cycles

Fig.6 Gate characteristics
